# NSN 5962-01-358-4068

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Between 0.442 inches and 0.460 inches

**Body Width:** 

Between 0.442 inches and 0.460 inches

**Body Height:** 

Between 0.060 inches and 0.100 inches

**Maximum Power Dissipation Rating:** 

440.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### **Storage Tempurature Range:**

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and burn in and monolithic and erasable and electrostatic sensitive

#### **Inclosure Material:**

Ceramic

#### **Inclosure Configuration:**

Leadless flat pack

# **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

# **Input Circuit Pattern:**

22 input

#### **Case Outline Source And Designator:**

C-4 mil-m-38510

# **Current Rating Per Characteristic:**

80.00 milliamperes reverse current, dc absolute

# **Terminal Surface Treatment:**

Solder

#### **Voltage Rating And Type Per Characteristic:**

5.5 volts power source

# **Capitance Rating Per Characteristic:**

6.00 input picofarads and 12.00 output picofarads

#### **Time Rating Per Chacteristic:**

1000.00 nanoseconds delay

#### **Memory Device Type:**

Prom

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# **Terminal Type And Quantity:**

28 leadless

# Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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